## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:

Yutaka	a TA	KIT.	A et a	ıl.
Applica	atio	n No	).:	Group Art Unit:
Filed:	Ex	amir	ner:	
For:	Pι	JLSE	E GEI	NERATING APPARATUS AND METHOD
				INFORMATION DISCLOSURE STATEMENT
PO Bo	x 14	450		Patents 13-1450
Sir:				
subjec	ed o	erta S. p	in info atent	ce with the duty of disclosure provisions of 37 CFR § 1.56, there is hereby ormation which the Examiner may consider material to the examination of the application. It is requested that the Examiner make this information of recordinal to the examination of the subject application.
	1.		Encl	osures accompanying this Information Disclosure Statement are:
		1c.		Form PTO-1449. Copies of IDS citations. An English language copy of search report(s) from a counterpart foreign application or a PCT International Search Report. English language translation (complete or relevant portion(s)) attached to each non-English language publication. Explanations of Relevancy of References (ATTACHMENT 1(e), hereto) for providing a concise explanation of each non-English publication.
	2.	$\boxtimes$	In a	eccordance with 37 CFR § 1.98, a concise explanation of what is presently lerstood to be the relevance of each non-English language publication is
		2a.		(Check appropriate Items 2a, 2b, 2c and/or 2d) satisfied because all non-English language publications were cited on the enclosed "English-language version of the search report or action which indicates the degree of relevance found by the foreign office". (See MPEP 609, Minimum Requirements for an Information Disclosure Statement, Part A(3): Concise Explanation of Relevance, pp. 600-100 to 600-101, Rev. 1,
		2b.		Feb. 2000.) set forth in the application.

	an English language translation of the Abstract is on-English language publication.  nment 1(e), hereto.
to be, material to patentabilit (other than search report(s)	he information cited in this Statement is, or is considered ty nor a representation that a search has been made from a counterpart foreign application or a PCT, if submitted herewith). 37 CFR §§ 1.97(g) and (h).
	Respectfully submitted,
	STAAS & HALSEY LLP
Dated: 4/20/04 1201 New York Ave., N.W., Suite 700 Washington, D.C. 20005 Telephone: (202) 434-1500 Facsimile: (202) 434-1501	By: Richard A. Gollhofer Registration No. 31,106

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# U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE

ATTORNEY DOCKET NO.	APPLICATION NO.		
826.1944	APPLICATION NO.		
FIRST NAMED INVENTOR	<del></del>		
Yutaka TAKITA et al.			

## LIST OF REFERENCES CITED BY APPLICANT

(Use several sheets if necessary)

ING DATE	GROUP ART UNIT
INGUATE	GROOF ART UNIT

#### **U.S. PATENT DOCUMENTS**

EXAMINER INITIAL		DOCUMENT NO.	DATE	NAME	CLASS	SUB- CLASS	FILING DATE
	AA	5,381,426	01/10/95	FONTANA et al.			
	АВ						
	AC						
	AD						

#### **FOREIGN PATENT DOCUMENTS**

	DOCUMENT NO.	DATE	COUNTRY	CLASS	SUB- CLASS	TRANSLATION YES NO
AE	6-302881	10/28/94	JAPAN			Abstract
AF	5-095152	04/16/93	JAPAN			Abstract
AG						

OTHER REFERENCES (INCLUDING AUTHOR, TITLE, DATE, PERTINENT PAGES, ETC.)

	THEK	REFERENCES (INCLUDING AUTHOR, TITLE, DATE, PERTINENT PAGES	, ETC.)	
			TRANSL YES	ATION NO
_	АН	T. KOBAYASHI et al., "Optical Pulse Compression Using High-Frequency Electrooptic Phase Modulation", IEEE Journal of Quantum Electronics, vol. 24, no. 2, 1988, pp. 382-387.		
	AI	E. YOSHIDA et al., "A 40-GHz 0.9-ps Regeneratively Mode-Locked Fiber Laser with a Tuning Range of 1530-1560 nm", IEEE Photonics Technology Letters, vol. 11, no. 12, 1999, pp. 1587-1589.		
	LA	H.F. LIU et al., "Generation of Wavelength-Tunable Transform-Limited Pulses from a Monolithic Passively Mode-Locked Distributed Bragg Reflector Semiconductor Laser", IEEE Photonics Technology Letters, 1995, vol. 7, No. 10, pp. 1139-1141.		
	AK	N. FROBERG et al., "Multi-gigabit short pulse generation from integrated DBR laser/modulators", IEEE Lasers and Electro-optics Society 1994 Annual Meeting Conference Proceedings, vol. 2, pp. 188-189.		
	AL	Volkan KAMAN et al., "Integrated Tandem Traveling-Wave Electroabsorption Modulators for > 100 Gbit/s OTDM Applications", IEEE Photonics Technology Letters, vol. 12, no. 11, 2000, pp. 1471-1473.		
EXAMINER		DATE CONSIDERED	<del></del>	

EXAMINER DATE CONSIDERED

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.